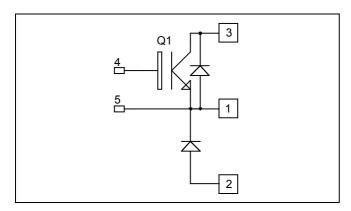


Buck Chopper Trench + Field Stop IGBT3 Power Module

$$V_{CES} = 1200V$$

 $I_{C} = 200A$ @ $Tc = 80$ °C



Application

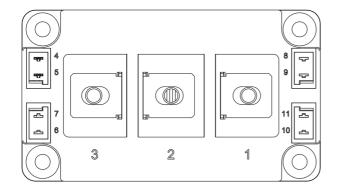
- AC and DC motor control
- Switched Mode Power Supplies

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- High level of integration
- M6 power connectors

Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- $\bullet \quad \text{Easy paralleling due to positive T_C of V_{CEsat}}$
- RoHS Compliant



Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1200	V
I_{C}	Continuous Collector Current	$T_C = 25^{\circ}C$	300	
	Continuous Conector Current	$T_C = 80$ °C	200	A
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	400	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25$ °C	1050	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^{\circ}C$	400A @ 1100V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				500	μΑ
V	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C	1.4	1.7	2.1	V
$V_{CE(sat)}$	Confector Emitter Saturation Voltage	$I_C = 200A$ $T_j = 125^{\circ}C$		2.0		·	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 8mA$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Typ	Max	Unit
C_{ies}	Input Capacitance	$V_{GE} = 0V, V_{CE} = 25V$		14		nF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		0.6		111
Q_{G}	Gate charge	V _{GE} =±15V, I _C =200A V _{CE} =600V		1.9		μC
T _{d(on)}	Turn-on Delay Time	Inductive Switching (25°C)		250		ns
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$		90		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 600 \text{V}$ $I_{\text{C}} = 200 \text{A}$		550		
T_{f}	Fall Time	$R_G = 3.6\Omega$		130		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C)	300		ns
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$		100		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 600V$ $I_{\text{C}} = 200A$		650		
T_{f}	Fall Time	$R_G = 3.6\Omega$		180		
Eon	Turn on Energy	$V_{GE} = \pm 15V \ V_{Bus} = 600V$ $T_j = 125^{\circ}C$		15		mJ
E_{off}	Turn off Energy	$I_C = 200A$ $R_G = 3.6\Omega$ $T_j = 125^{\circ}C$;	35		1113
I_{sc}	Short Circuit data	$V_{GE} \le 15V$; $V_{Bus} = 900V$ $t_p \le 10\mu s$; $T_i = 125^{\circ}C$		800		A

Reverse diode ratings and characteristics

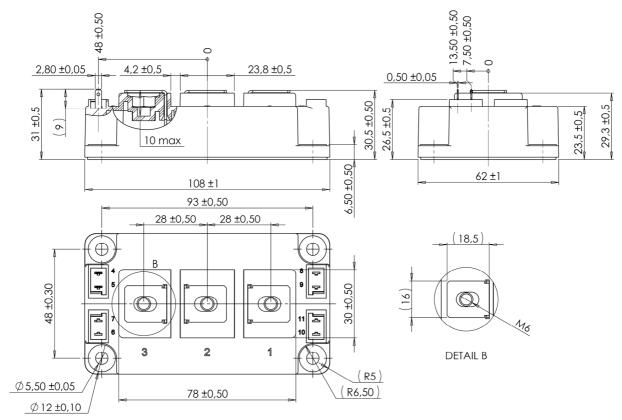
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I_{RRM}	Maximum Reverse Leakage Current	V _R =1200V	$T_i = 25$ °C $T_i = 125$ °C			750 1000	μА
I_{F}	DC Forward Current		$Tc = 80^{\circ}C$		200		A
V_{F}	Diode Forward Voltage	$I_F = 200A$ $V_{GE} = 0V$	$T_j = 25^{\circ}C$		1.6	2.1	V
V F			$T_i = 125$ °C		1.6		v
+	Payarsa Pagayary Tima		$T_j = 25^{\circ}C$		170		ns
t_{rr}	Reverse Recovery Time		$T_j = 125$ °C		280		115
	Davaga Dasayaw Changa	$I_F = 200A$ $V_R = 600V$	$T_j = 25$ °C		22		C
Q _{rr}	Reverse Recovery Charge	$di/dt = 3500A/\mu s$	$T_{j} = 125^{\circ}C$		40		μС
E _{rr}	Reverse Recovery Energy]	$T_j = 25$ °C		9		mJ
Lit	Reverse Recovery Energy		$T_{j} = 125^{\circ}C$		16		1113



Thermal and package characteristics

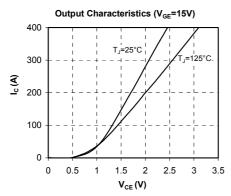
Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance		IGBT			0.12	°C/W
KthJC			Diode			0.20	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		125	
Torque	Mounting torque	For terminals	M6	3		5	N.m
		To Heatsink	M6	3		5	18.111
Wt	Package Weight					350	g

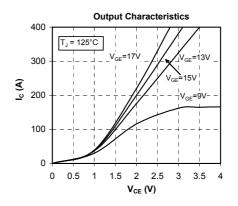
D3 Package outline (dimensions in mm)

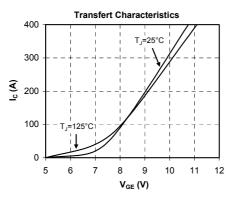


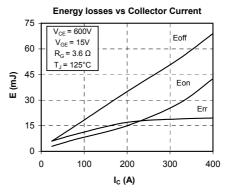


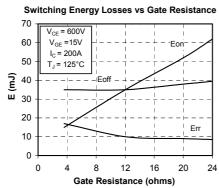
Typical Performance Curve

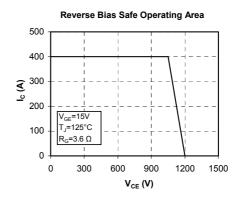


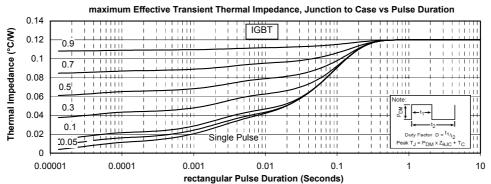




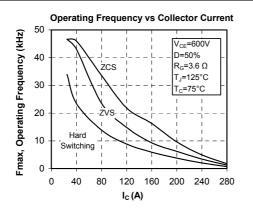


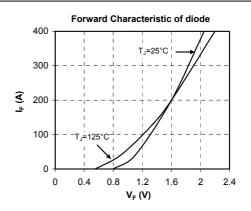


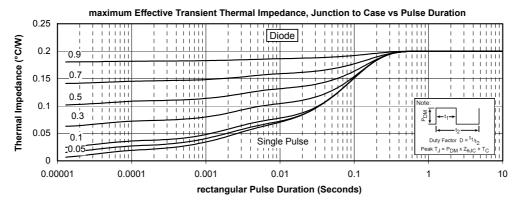












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